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Data Sheet January 2002

8A, 400V - 600V Hyperfast Diodes

The RHRP840 and RHRP860 are hyperfast diodes with soft recovery characteristics (t_{rr} < 30ns). They have half the recovery time of ultrafast diodes and are silicon nitride passivated ion-implanted epitaxial planar construction.

These devices are intended for use as freewheeling/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

Formerly developmental type TA49059.

Ordering Information

PART NUMBER	PACKAGE	BRAND
RHRP840	TO-220AC	RHRP840
RHRP860	TO-220AC	RHRP860

NOTE: When ordering, use the entire part number.

Symbol



Features

•	Hyperfast with Soft Recovery<30ns
•	Operating Temperature
•	Reverse Voltage Up To

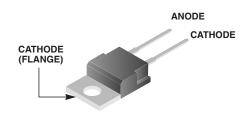
- · Avalanche Energy Rated
- Planar Construction

Applications

- Switching Power Supplies
- · Power Switching Circuits
- · General Purpose

Packaging

JEDEC TO-220AC



Absolute Maximum Ratings T _C = 25°C, Unless Otherwise Specified			
	RHRP840	RHRP860	UNITS
Peak Repetitive Reverse Voltage	400	600	V
Working Peak Reverse VoltageV _{RWM}	400	600	V
DC Blocking Voltage	400	600	V
Average Rectified Forward Current	8	8	Α
Repetitive Peak Surge Current	16	16	Α
Nonrepetitive Peak Surge Current	100	100	Α
Maximum Power Dissipation	75	75	W
Avalanche Energy (See Figures 10 and 11)	20	20	mJ
Operating and Storage Temperature	-65 to 175	-65 to 175	oC

RHRP840, RHRP860

Electrical Specifications $T_C = 25^{\circ}C$, Unless Otherwise Specified

	TEST CONDITION		RHRP840		RHRP860			
SYMBOL		MIN	TYP	MAX	MIN	TYP	MAX	UNITS
V _F	I _F = 8A	-	-	2.1	-	-	2.1	V
	$I_F = 8A, T_C = 150^{\circ}C$	-	-	1.7	-	-	1.7	V
I _R	V _R = 400V	-	-	100	-	-	-	μА
	V _R = 600V	-	-	-	-	-	100	μА
	V _R = 400V, T _C = 150°C	-	-	500	-	-	-	μА
	V _R = 600V, T _C = 150°C	-	-	-	-	-	500	μА
t _{rr}	$I_F = 1A$, $dI_F/dt = 200A/\mu s$	-	-	30	-	-	30	ns
	$I_F = 8A$, $dI_F/dt = 200A/\mu s$	-	-	35	-	-	35	ns
ta	$I_F = 8A$, $dI_F/dt = 200A/\mu s$	-	18	-	-	18	-	ns
t _b	$I_F = 8A$, $dI_F/dt = 200A/\mu s$	-	10	-	-	10	-	ns
Q _{RR}	$I_F = 8A$, $dI_F/dt = 200A/\mu s$	-	56	-	-	56	-	nC
СЈ	V _R = 10V, I _F = 0A	-	25	-	-	25	-	pF
$R_{ heta JC}$		-	-	2	-	-	2	°C/W

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 μ s, D = 2%).

 I_R = Instantaneous reverse current.

 t_{rr} = Reverse recovery time (See Figure 9), summation of t_a + t_b .

t_a = Time to reach peak reverse current (See Figure 9).

 t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

 Q_{RR} = Reverse recovery charge.

CJ = Junction capacitance.

 $R_{\theta JC}$ = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

Typical Performance Curves

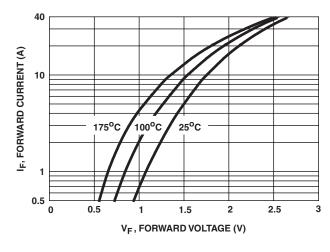


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

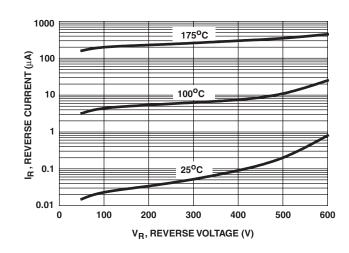


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

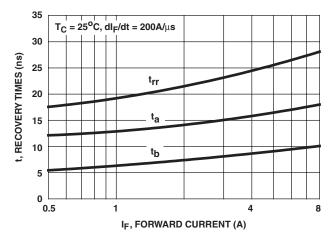


FIGURE 3. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

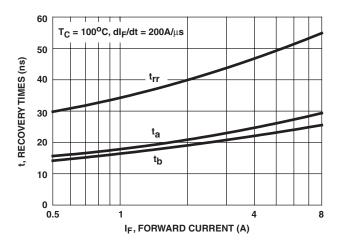


FIGURE 4. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

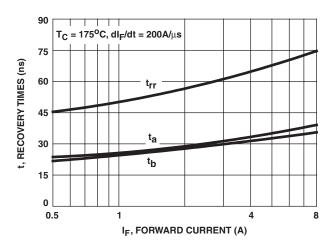


FIGURE 5. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

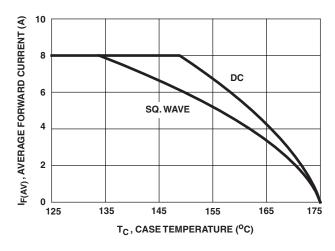


FIGURE 6. CURRENT DERATING CURVE

RHRP840, RHRP860 Rev. B

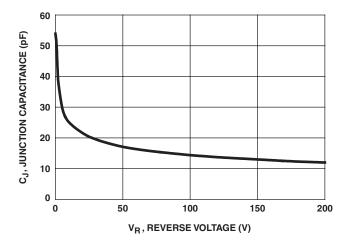


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

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Test Circuits and Waveforms

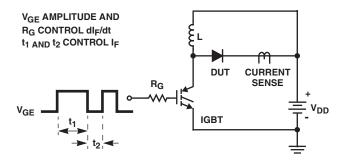


FIGURE 8. t_{rr} TEST CIRCUIT

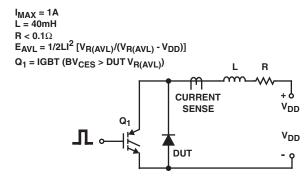


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

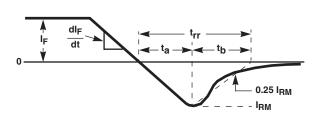


FIGURE 9. t_{rr} WAVEFORMS AND DEFINITIONS

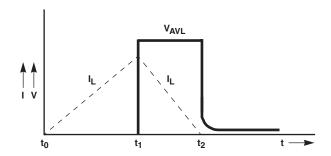
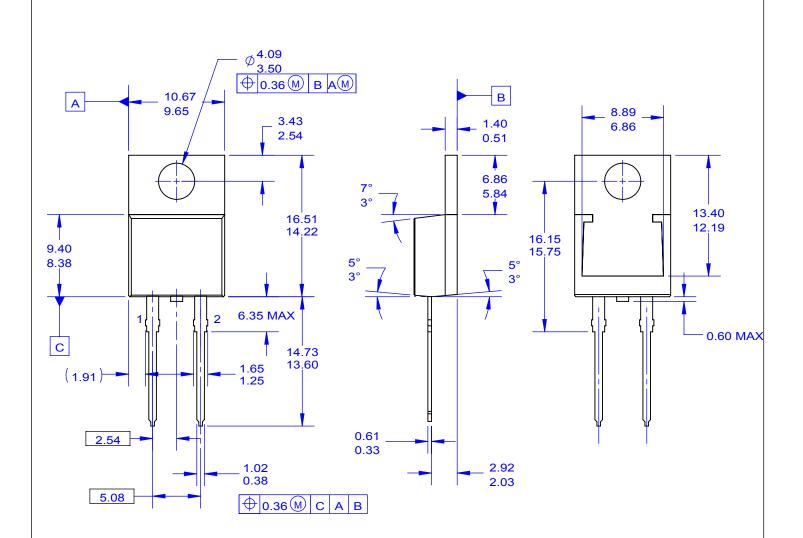
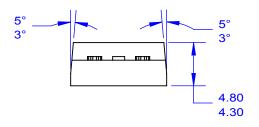


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS







NOTES:

- A. PACKAGE REFERENCE: JEDEC TO220,ISSUE K, VARIATION AC,DATED APRIL 2002.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSION AND TOLERANCE AS PER ASME Y14.5-2009.
- D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
- E. DRAWING FILE NAME: TO220A02REV5

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